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ROHS

HALOGEN FREE

# Hyperfast Rectifier, 30 A FRED Pt® G5



PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub>	30 A			
V <sub>R</sub>	600 V			
V <sub>F</sub> at I <sub>F</sub> at 125 °C	1.3 V			
t <sub>rr</sub> (typ.)	22			
I <sub>FSM</sub>	310			
T <sub>J</sub> max.	175 °C			
Package	TO-247AD 2L			
Circuit configuration	Single			

### **LINKS TO ADDITIONAL RESOURCES**



#### **FEATURES**

- Hyperfast and optimized Q<sub>rr</sub>
- Best in class forward voltage drop and switching losses trade off



• 175 °C maximum operating junction temperature

Polyimide passivation

- AEC-Q101 qualified meets JESD 201 class 1A whisker test
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912">www.vishay.com/doc?99912</a>

#### **DESCRIPTION / APPLICATIONS**

Featuring a unique combination of low conduction and switching losses, this rectifier is the right choice for soft switched and resonant converters, as well as medium frequency hard switching converters. This device is specifically designed to improve efficiency of high speed LLC output rectification stages of EV / HEV on-board battery chargers

### **MECHANICAL DATA**

Case: TO-247AD 2L

Molding compound meets UL 94 V-0 flammability rating **Terminal:** matte tin plated leads, solderable per J-STD-002

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Repetitive peak reverse voltage	$V_{RRM}$		600	V	
Average rectified forward current	I <sub>F(AV)</sub>	T <sub>C</sub> = 117 °C, D = 0.50	30		
Non-repetitive peak surge current	I <sub>FSM</sub>	$T_C = 25$ °C, $t_p = 10$ ms, sine wave	310	Α	
Repetitive peak forward current	I <sub>FRM</sub>	$T_C = 117  ^{\circ}C,  D = 0.50,  f = 20  \text{kHz}$	60		
Operating junction and storage temperature	T <sub>J</sub> , T <sub>Stg</sub>		-55 to +175	°C	

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)						
PARAMETER	SYMBOL TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	$V_{BR}, V_{R}$	$I_R = 100 \mu A$	600	-	-	
Forward voltage	W	I <sub>F</sub> = 30 A	-	1.6	2.1	V
Forward voitage	V <sub>F</sub>	I <sub>F</sub> = 30 A, T <sub>J</sub> = 125 °C	-	1.3	-	
Deverage leake as a surrent		$V_R = V_R$ rated	-	-	20	
Reverse leakage current I <sub>R</sub>		$T_J = 125 ^{\circ}\text{C}, V_R = V_R \text{ rated}$	-	-	500	μA
Junction capacitance	C <sub>T</sub>	V <sub>R</sub> = 200 V	-	36	-	pF
Series inductance	L <sub>S</sub>	Measured to lead 5 mm from package body	-	8	-	nH



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<b>DYNAMIC RECOVERY CHARACTERISTICS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CO	TEST CONDITIONS		TYP.	MAX.	UNITS
		$I_F = 1.0 \text{ A}, dI_F/dt = 10$	$I_F = 1.0 \text{ A}, dI_F/dt = 100 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$		22	-	
Reverse recovery time	t <sub>rr</sub>	T <sub>J</sub> = 25 °C		-	39	-	ns
		T <sub>J</sub> = 125 °C		-	50	-	
Dook recovery ourrent	I <sub>RRM</sub>	T <sub>J</sub> = 25 °C	$I_F = 20 \text{ A}$ $dI_F/dt = 1000 \text{ A/}\mu\text{s}$ $V_R = 400 \text{ V}$	-	14	-	Α
Peak recovery current		T <sub>J</sub> = 125 °C		-	24	-	A
Devenue ve estrem celeuras	0	T <sub>J</sub> = 25 °C		-	253	-	~C
Reverse recovery charge Q <sub>rr</sub>	T <sub>J</sub> = 125 °C		=	785	-	nC	
Poverse recovery time		T <sub>J</sub> = 25 °C		-	41	-	no
Reverse recovery time	t <sub>rr</sub>	T <sub>J</sub> = 125 °C		-	56	-	ns
Peak recovery current I <sub>RRM</sub>	T <sub>J</sub> = 25 °C	I <sub>F</sub> = 30 A dI <sub>F</sub> /dt = 1000 A/μs V <sub>R</sub> = 400 V	-	16	-	Α	
	T <sub>J</sub> = 125 °C		=	27	-	A	
Reverse recovery charge Q <sub>rr</sub>		T <sub>J</sub> = 25 °C	••	-	306	-	nC
	T <sub>J</sub> = 125 °C		-	952	-	IIC	

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Thermal resistance, junction-to-case	R <sub>thJC</sub>		-	-	1.1	°C/W
Weight			-	5.5	-	g
weight			-	0.2	-	oz.
Mounting torque			6 (5)	-	12 (10)	kgf · cm (lbf · in)
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-55	-	175	°C
Marking device		Case style: TO-247AD 2L		E5PX3	3006LH	

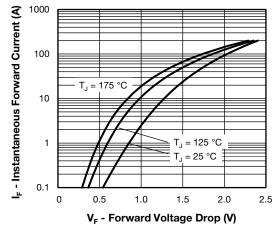


Fig. 1 - Typical Forward Voltage Drop Characteristics

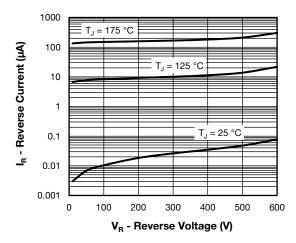


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

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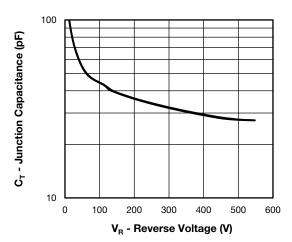


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

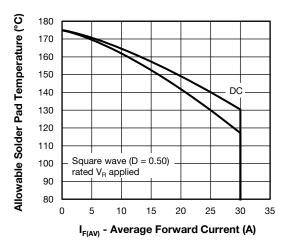


Fig. 4 - Maximum Allowable Case Temperature vs.

Average Forward Current

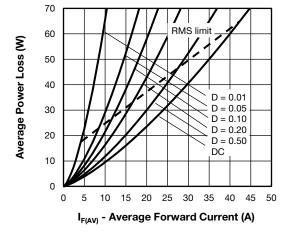


Fig. 5 - Average Power Loss vs. Average Forward Current

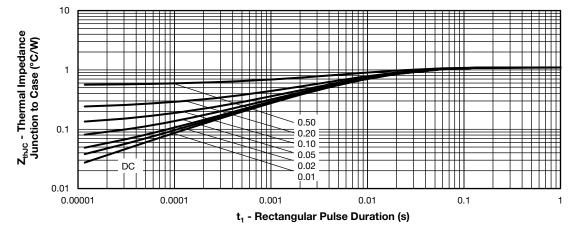


Fig. 6 - Thermal Impedance  $Z_{\text{thJC}}$  - Characteristics

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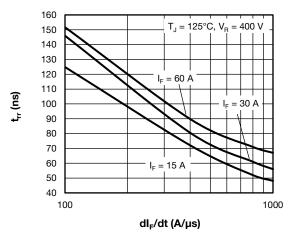


Fig. 7 - Typical Reverse Recovery Time vs. dl<sub>F</sub>/dt

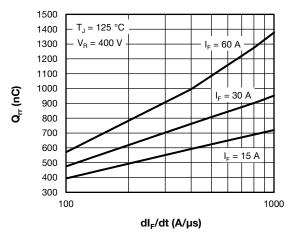


Fig. 8 - Typical Reverse Recovery Charge vs. dl<sub>F</sub>/dt

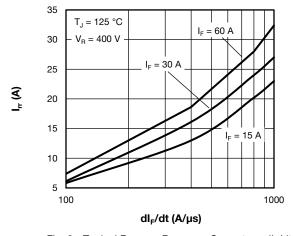


Fig. 9 - Typical Reverse Recovery Current vs.  $dI_F/dt$ 

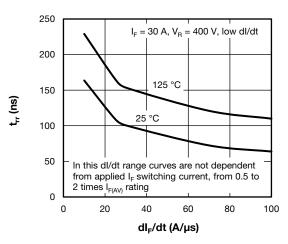


Fig. 10 - Typical Reverse Recovery Time vs. dl<sub>F</sub>/dt

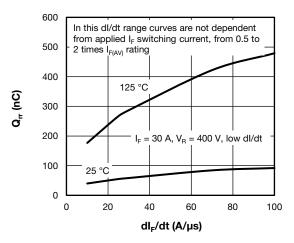


Fig. 11 - Typical Reverse Recovery Charge vs. dl<sub>F</sub>/dt

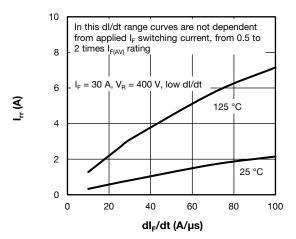


Fig. 12 - Typical Reverse Recovery Current vs. dl<sub>F</sub>/dt

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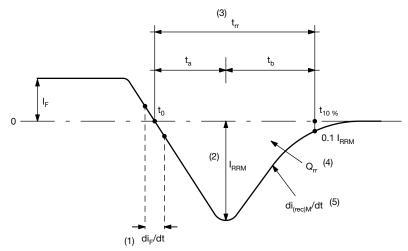


Fig. 13 - Reverse Recovery Waveform and Definitions

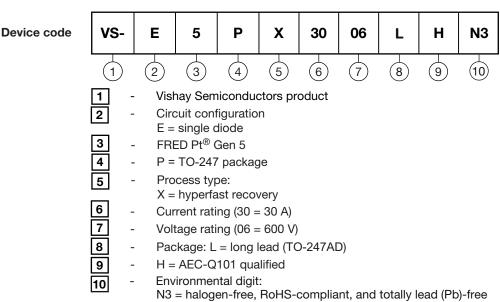
#### **Notes**

- (1) di<sub>E</sub>/dt rate of change of current through zero crossing
- (2) I<sub>RRM</sub> peak reverse recovery current
- (3) t<sub>rr</sub> reverse recovery time measured from t<sub>0</sub>, crossing point of negative going I<sub>F</sub>, to point t<sub>10%</sub>, 0.1 I<sub>RBM</sub>
- $^{(4)}$   $Q_{rr}$  area under curve defined by  $t_0$  and  $t_{10}$  %

$$Q_{rr} = \int_{t_0}^{t_{10\%}} I(t) dt$$

(5) di<sub>(rec)</sub>M/dt - peak rate of change of current during t<sub>b</sub> portion of t<sub>rr</sub>

### **ORDERING INFORMATION TABLE**



ORDERING INFORMATION (Example)					
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION		
VS-E5PX3006LHN3	25	500	Antistatic plastic tube		

LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95536			
Part marking information	www.vishay.com/doc?95648			



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